

### **Features**

- · Trench Power MV MOSFET Technology
- · Excellent Package for Heat Dissipation
- High Density Cell Design for Low R<sub>DS(on)</sub>
- · Epoxy Meets UL 94 V-0 Flammability Rating
- Moisture Sensitivity Level 3
- Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

# **Maximum Ratings**

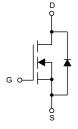
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 100°C/W Junction to Ambient

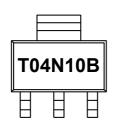
Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V <sub>DS</sub>	100	V
Gate-Source Volltage	V <sub>GS</sub>	±20	V
Continuous Drain Current	I <sub>D</sub>	4	Α
Pulsed Drain Current	I <sub>DM</sub>	20	Α
Total Power Dissipation	P <sub>D</sub>	1.25	W
Single Pulsed Avalanche Energy <sup>(Note 2)</sup>	E <sub>AS</sub>	16	mJ

## Note:

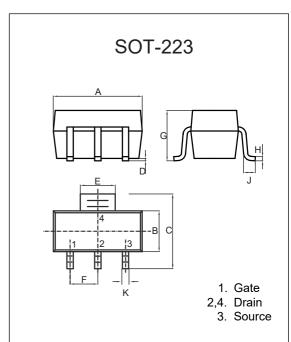
- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2.  $V_{DD}$ =50V,  $V_{GS}$ =10V, L=0.5mH,  $I_{AS}$ =8A.

# **Internal Structure and Marking Code**





# N-CHANNEL MOSFET



DIMENSIONS						
DIM	INCHES		MM		NOTE	
	MIN	MAX	MIN	MAX	NOTE	
Α	0.248	0.264	6.30	6.70		
В	0.130	0.146	3.30	3.70		
С	0.264	0.287	6.70	7.30		
D	0.001	0.004	0.02	0.10		
Е	0.114	0.122	2.90	3.10		
F	0.091		2.30		TYP.	
G		0.071		1.80		
Н	0.009	0.014	0.23	0.35		
J	0.030		0.75			
K	0.026	0.033	0.66	0.84		



# Electrical Characteristics @ 25°C (Unless Otherwise Specified)

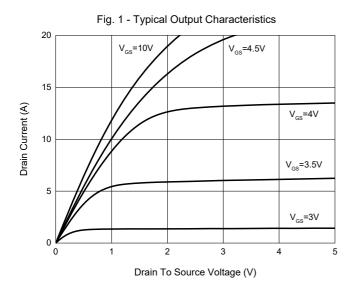
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static Characteristics				1	1	ı
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS}$ =0V, $I_{D}$ =250 $\mu$ A	100			V
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =±20V			±100	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V, V <sub>GS</sub> =0V			1	μA
Gate-Threshold Voltage <sup>(Note 3)</sup>	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_D=250\mu A$	1.1	2.0	3	V
Drain-Source On-Resistance <sup>(Note 3)</sup>	D	V <sub>GS</sub> =10V, I <sub>D</sub> =5A		77	105	105 120 mΩ
	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =3.2A		90	120	
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =4A		0.86	1.2	V
Continuous Body Diode Current	Is				4	Α
Dynamic Characteristics(Note 4)			·			
Input Capacitance	C <sub>iss</sub>			1143		pF
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =50V, $V_{GS}$ =0V,f=1MHz		41		
Reverse Transfer Capacitance	C <sub>rss</sub>			33		
Gate Resistance	R <sub>G</sub>	f=1MHz, Open drain		0.94		Ω
Total Gate Charge	Qg			22		
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 50V, V_{GS} = 10V, I_{D} = 5A$		5.9		20
Gate-Drain Charge	$Q_{gd}$			3.8		nC
Reverse Recovery Charge	Q <sub>rr</sub>	1 -5 \ di/dt-100 \ \ /u \ \		58		
Reverse Recovery Time	t <sub>rr</sub>	I <sub>S</sub> =5A, di/dt=100A/μs		57		
Turn-On Delay Time	t <sub>d(on)</sub>			10		
Turn-On Rise Time	t <sub>r</sub>	V <sub>GS</sub> =10V,V <sub>DD</sub> =50V,I <sub>D</sub> =5A		24		ns
Turn-Off Delay Time	t <sub>d(off)</sub>	$R_G=6\Omega$		25		
Turn-Off Fall Time	t <sub>f</sub>			30		

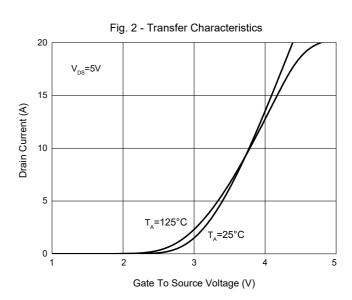
Note 3. Pulse Test : Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2%.

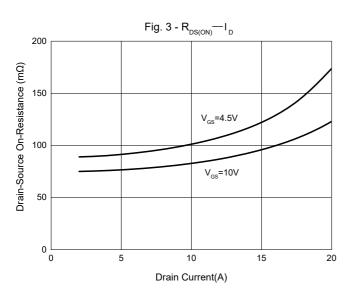
4. Guaranteed by Design, Not Subject to Production Testing.

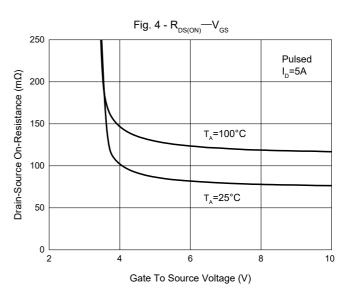


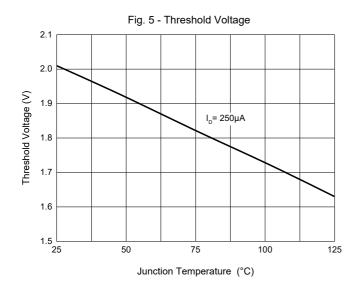
## **Curve Characteristics**

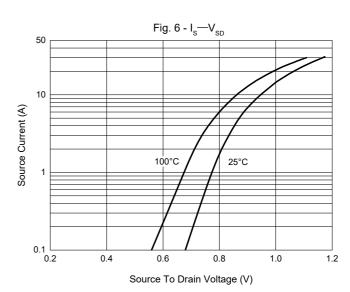






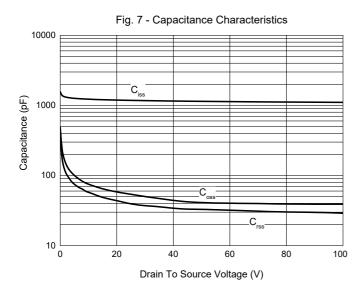


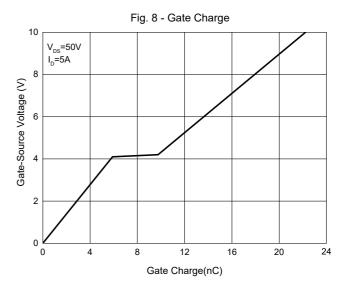


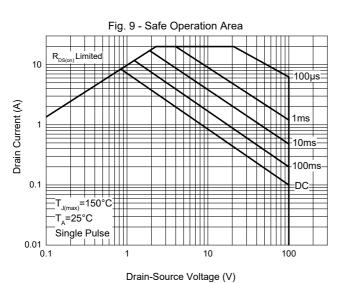


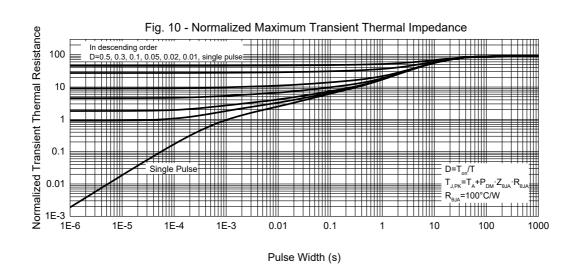


## **Curve Characteristics**











# **Ordering Information**

Device	Packing	
Part Number-TP	Tape&Reel: 2.5Kpcs/Reel	

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